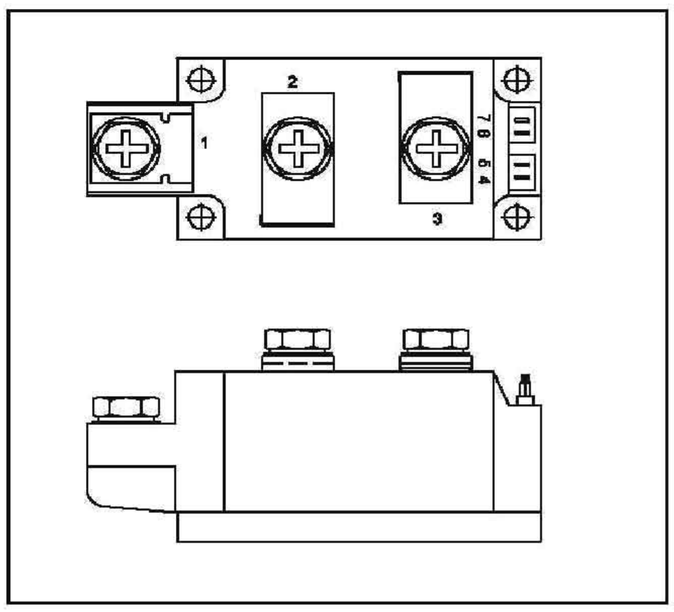
Ruttonsha International Rectifier Ltd.

POWER MODULES

IRK.350 SERIES
High Voltage Diode/Diode

FEATURES

- *High voltage.*
- *Electrically isolated base plate.*
- *3000 V_{RMS} isolating voltage.*
- *Industrial standard package.*
- *Simplified mechanical designs, rapid assembly.*
- *High surge capability.*
- *Large creepage distances.*
- *Aluminum Nitride*



DESCRIPTION

This IRK series of Power Modules uses power diodes in three basic configurations. The semiconductors are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges. These modules are intended for general purpose applications such as battery chargers, welders and plating equipment.

MAJOR RATINGS & CHARACTERISTICS

Parameters		IRK.350	Units
$I_{F(AV)}$	@ $T_C = 100^0C$	350	A
$I_{F(RMS)}$		502	A
I_{FSM}	@ 50 Hz	10110	A
I^2t	@ 50 Hz	511	kA^2s
$I^2\sqrt{t}$		5110	$kA^2\sqrt{s}$
V_{RRM} range		400 to 1600	V
T_J		-40 to 135	^0C

IRK .350 SERIES

ELECTRICAL SPECIFICATION

VOLTAGE RATINGS

Type Number	Voltage Code	V_{RRM} , max. repetitive peak reverse and off-state voltage blocking voltage V	V_{RSM}, max. non-repetitive peak reverse voltage V	I_{RRM} max. @ 150°C mA
IRK.350	04	400	500	50
	06	600	700	50
	08	800	900	50
	10	1000	1100	50
	12	1200	1300	50
	14	1400	1500	50
	16	1600	1700	50

FORWARD CONDUCTION

	Parameters	IRK.350)	Units	Conditions	
$I_{F(AV)}$	Max. average forward current	350	A	180°C conduction, half sine wave	
	@ case temperature	100	°C		
$I_{F(RMS)}$	Max. RMS forward current	502	A	as AC switch	
I_{FSM}	Max. peak, one cycle forward non-repetitive surge current	10110	A	t = 10ms	Sinusoidal half wave, Initial $T_J = T_J$ max.
I^2t	Maximum I^2t for fusing	511	kA^2s	t = 10ms	Sinusoidal half wave, Initial $T_J = T_J$ max.
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	5110	$kA^2\sqrt{s}$	t = 0.1 to 10ms. No voltage reapplied.	
$V_{F(TO)}$	Threshold voltage	0.69	V	$T_J = T_J$ max.	
r_t	Forward slope resistance	0.59	mΩ	$T_J = T_J$ max.	
V_{FM}	Max. forward voltage drop	1.25	V	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = T_J$ max., 180° conduction AV. power = $V_{F(TO)} \times I_{F(AV)} + r_1 \times (I_{F(RMS)})^2$	

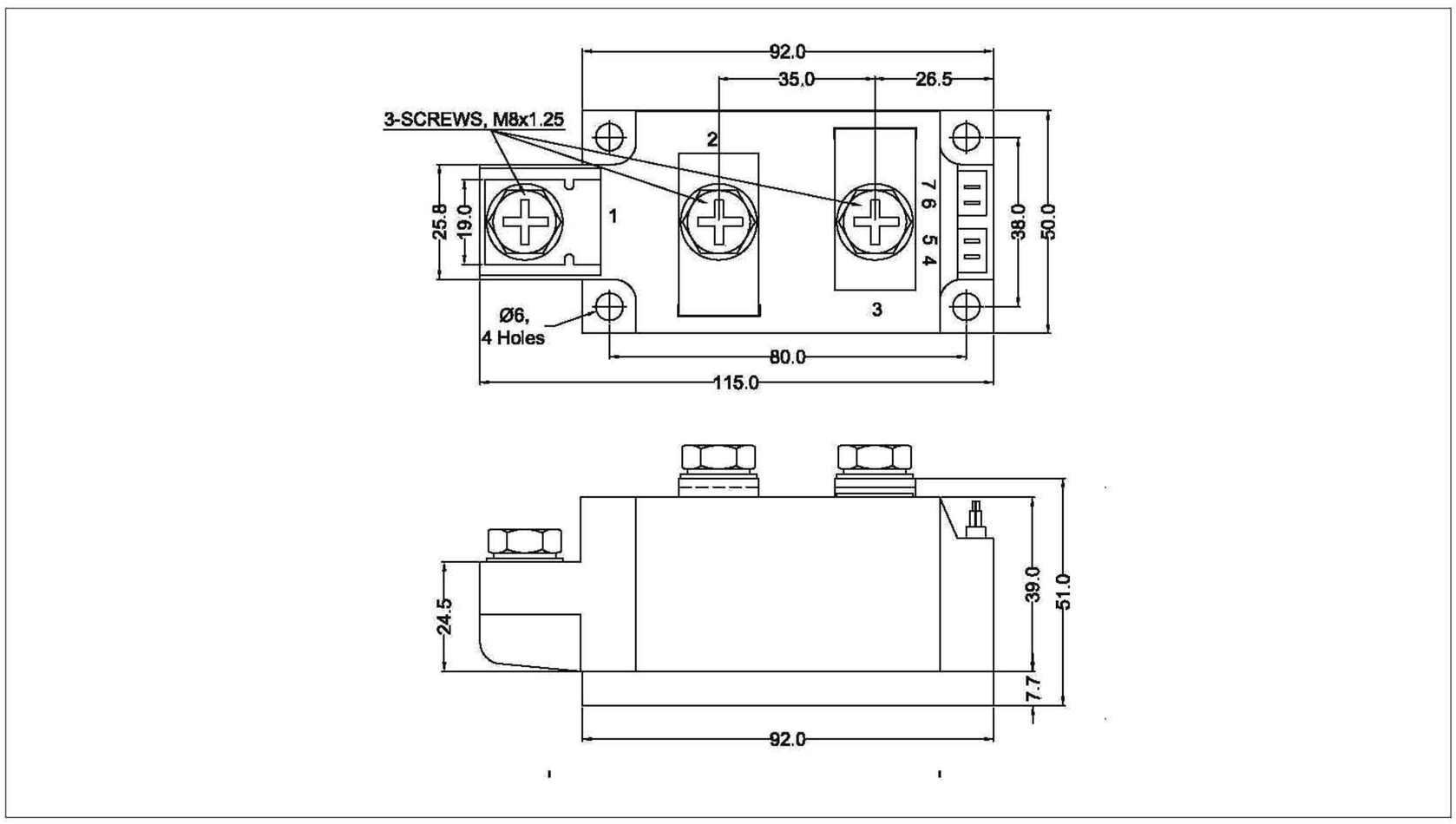
THERMAL AND MECHANICAL SPECIFICATIONS

	Parameters		IRK.350	Units	Conditions	
T_J	Junction operating temperature		-40 to 135	^{0}C		
T_{stg}	Storage temperature range		-40 to 150	^{0}C		
R_{thj-c}	Max. internal thermal resistance, junction to case		0.125	K/W	IRKD../IRKJ../IRKC..	Per junction, DC operation
R_{thC-S}	Thermal resistance, case to heatsink		0.035	K/W	Mounting surface flat, smooth and greased	
T	Mounting torque ±10%	Module to heatsink	4 to 6	Nm	A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound.	
		Busbar to module	8 to 10	Nm		
Wt	Approximate weight		600	g		

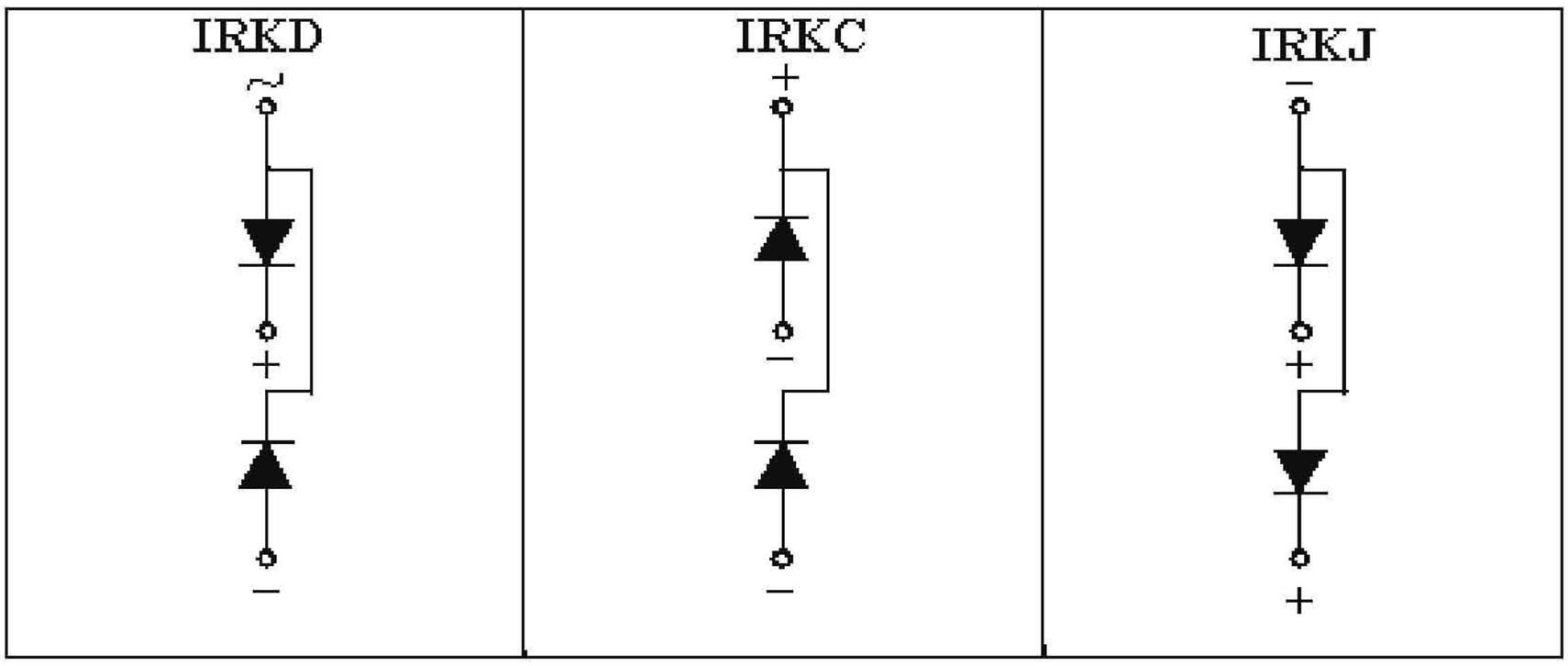
BLOCKING

	Parameter	IRK.350	Units	Conditions
I_{RRM}	Max. peak reverse leakage current	50	mA	T_J = 150^{0}C
V_{INS}	RMS isolation voltage	3000	V	50 Hz,circuit to base,all terminals shorted, t=1sec

OUTLINE DIAGRAM



Circuit Configuration Table



Ordering Information Table

IRK	D	350	/	16
①	②	③		④

① - Module type

② - Circuit configuration (See Circuit Configuration table)

③ - Current Code

④ - Voltage Code (See Voltage Ratings table)

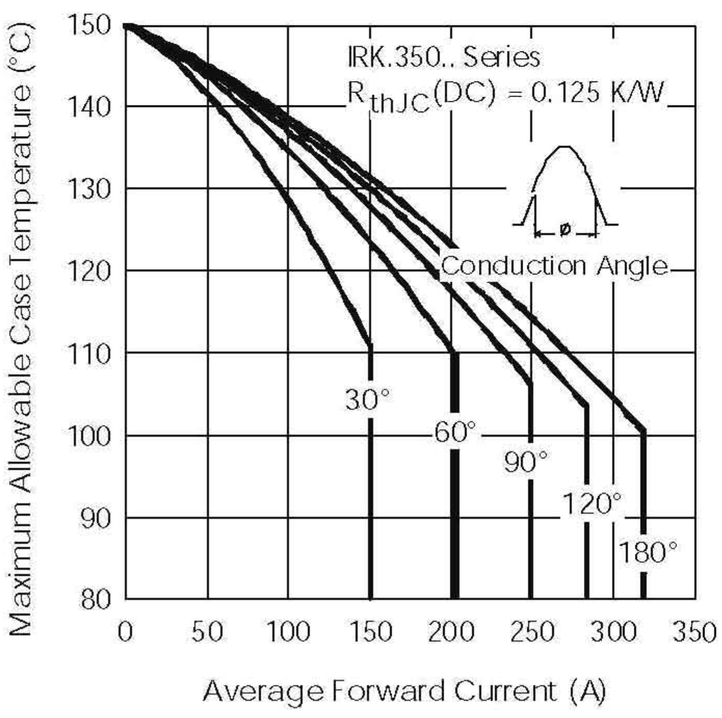


Fig. 1 -Current Ratings Characteristics

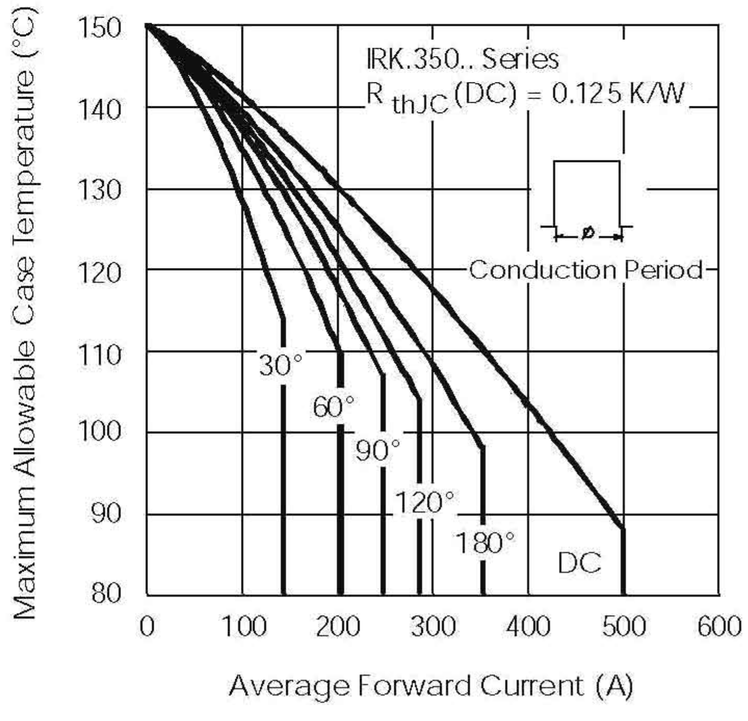


Fig. 2 -Current Ratings Characteristics

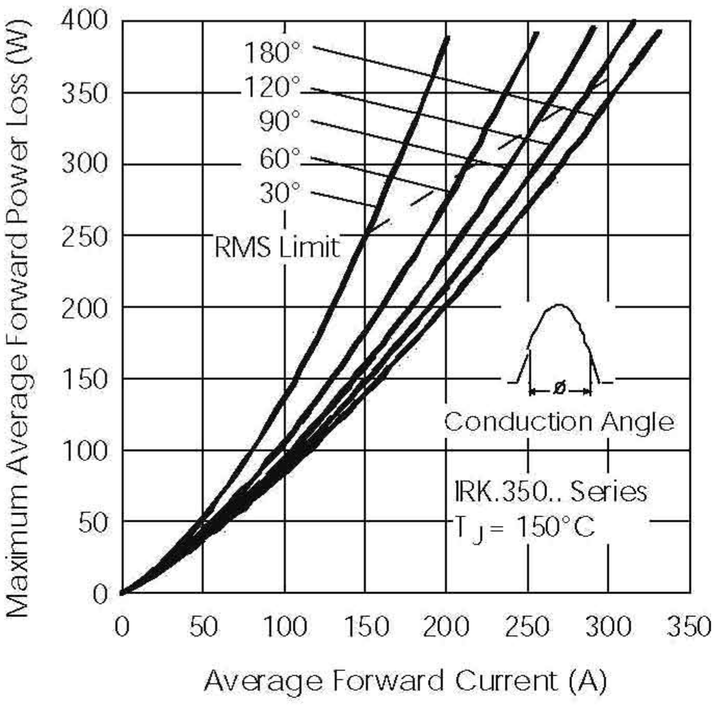


Fig. 3 - Forward Power Loss Characteristics

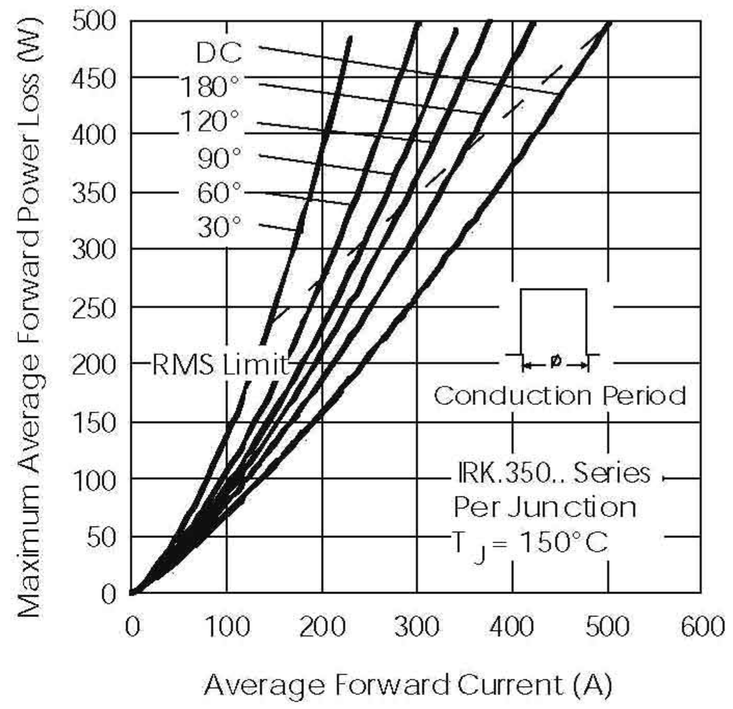


Fig. 4 - Forward Power Loss Characteristics

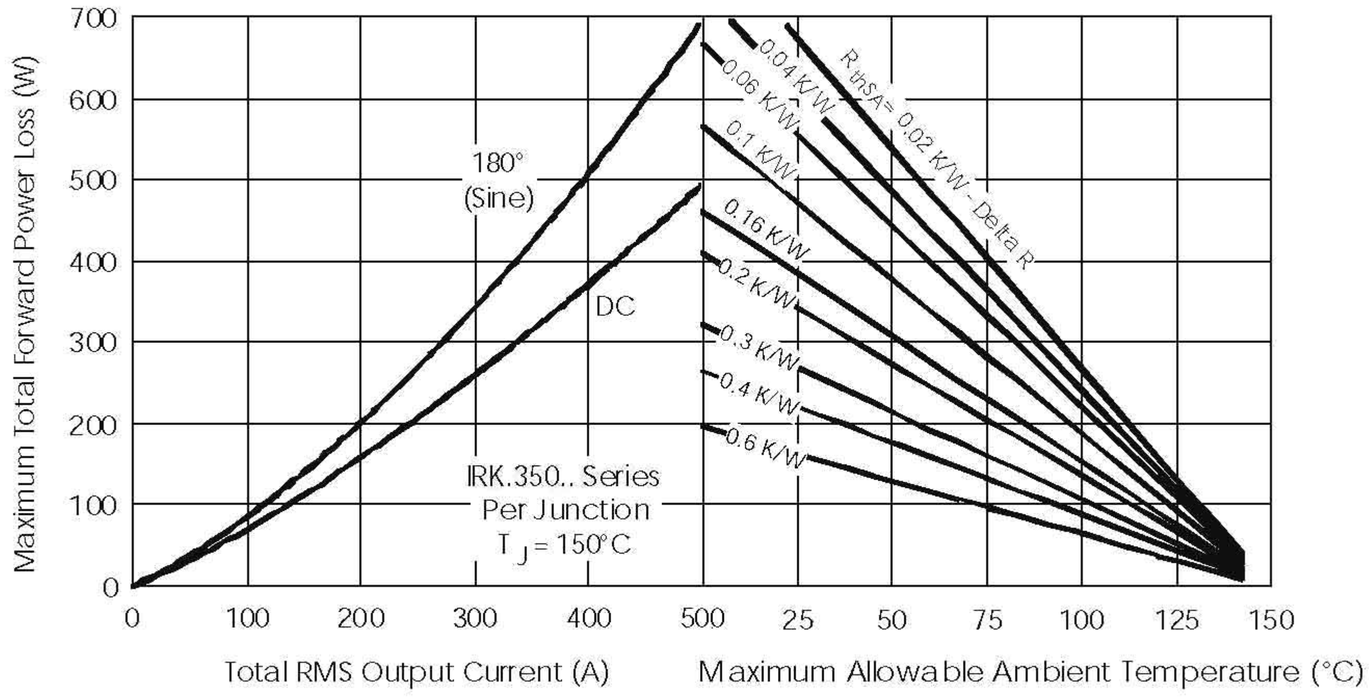


Fig. 5 -Forward Power Loss Characteristics

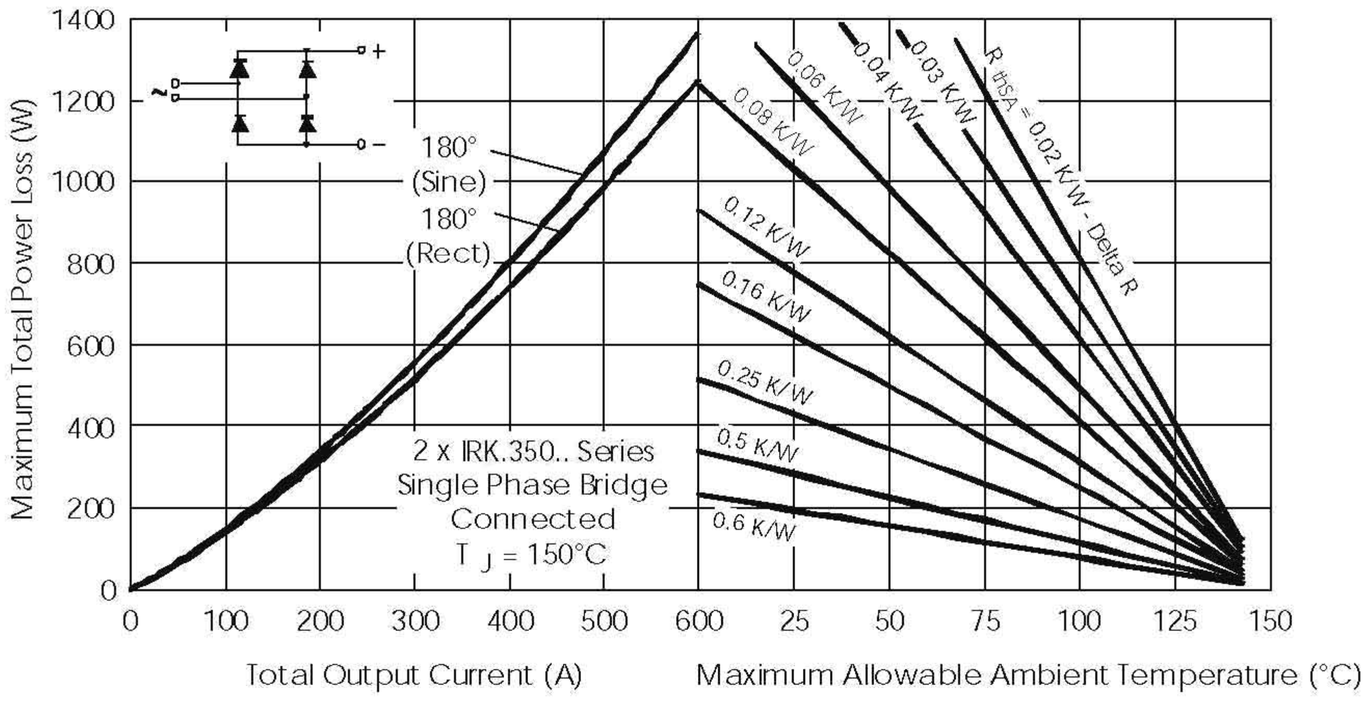


Fig. 6 -Forward Power Loss Characteristics

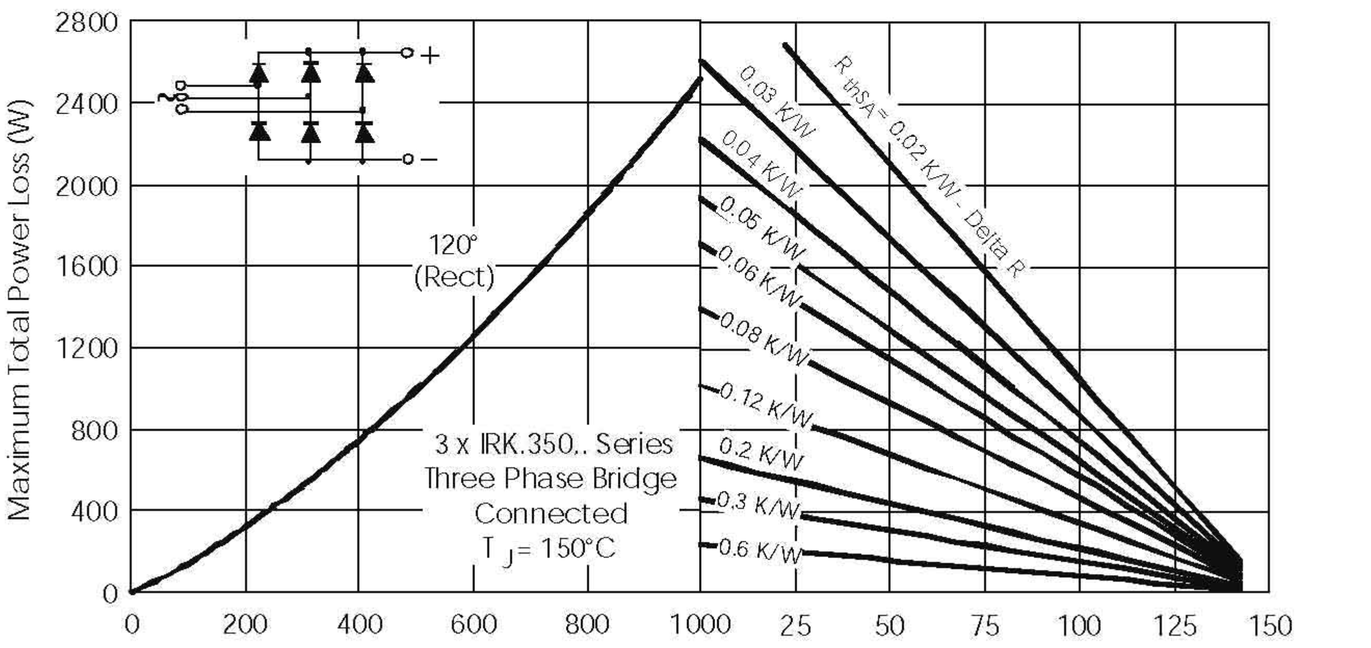


Fig. 7 - Forward Power Loss Characteristics

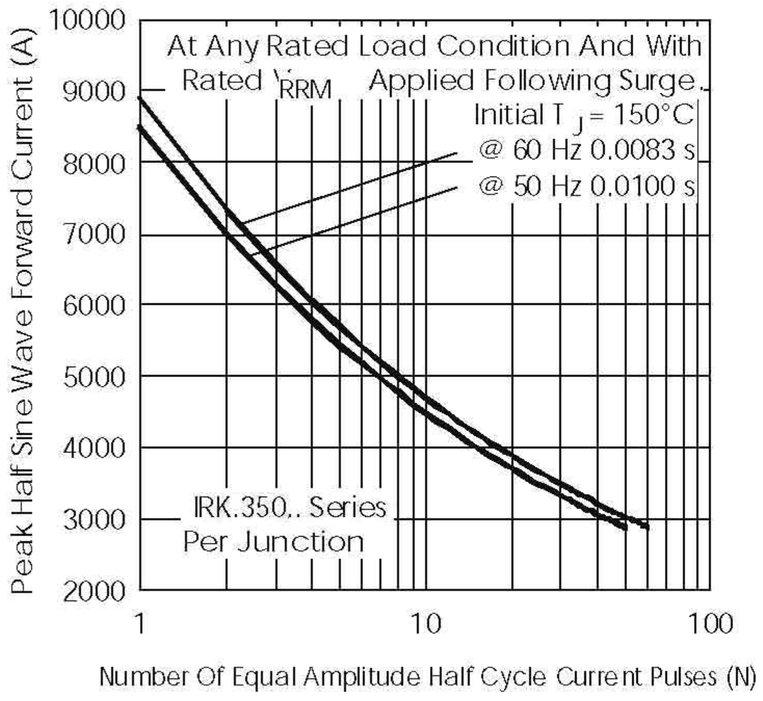


Fig. 8 -Maximum Non-Repetitive Surge Current

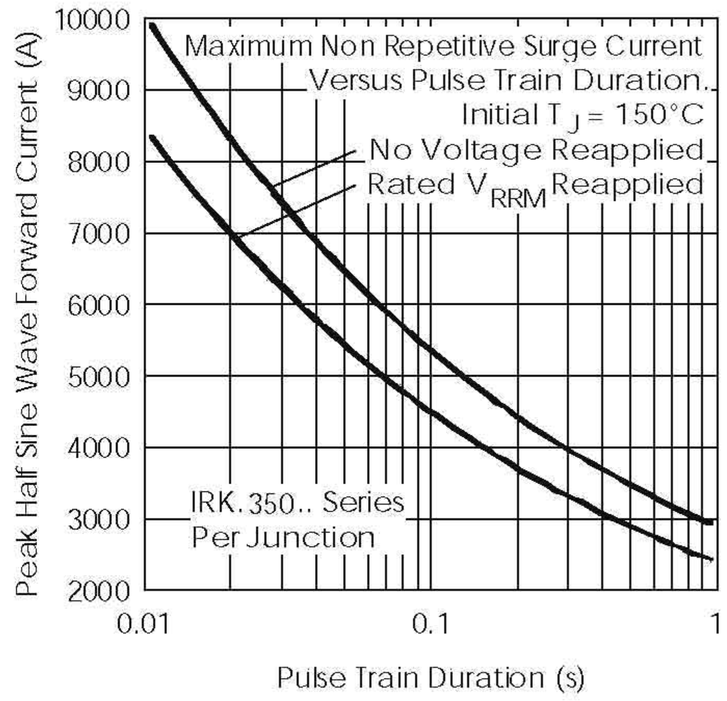


Fig. 9 -Maximum Non-Repetitive Surge Current

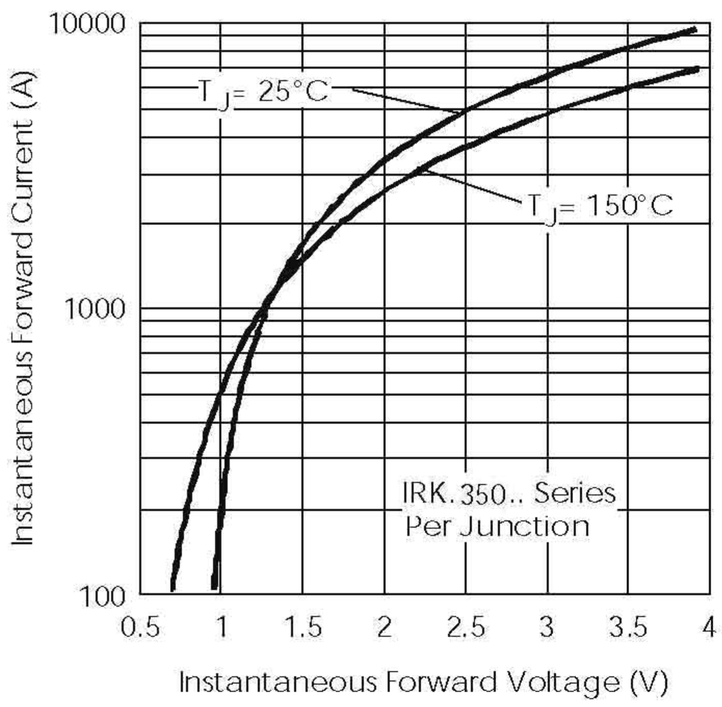


Fig. 10 - Forward Voltage Drop Characteristics

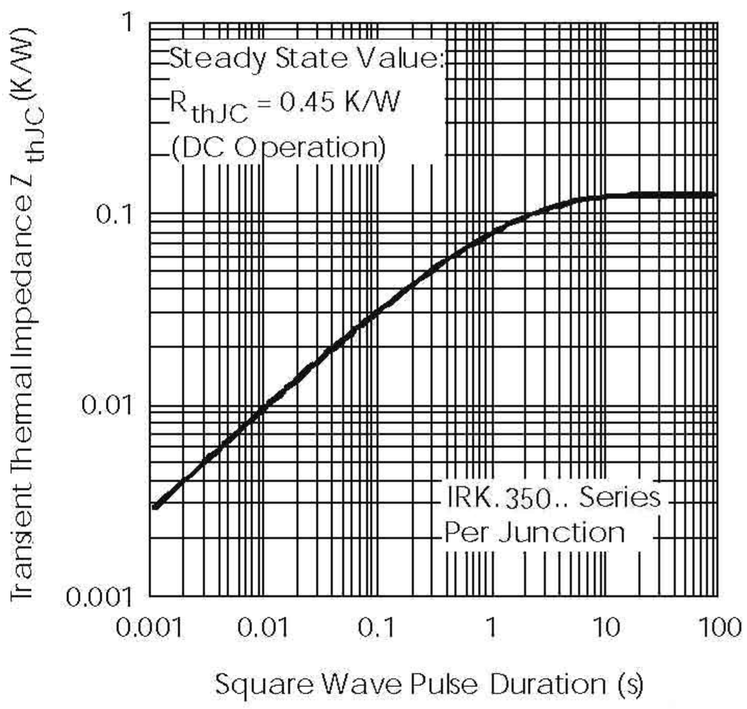


Fig. 11 - Thermal Impedeance Z_{thJC} Characteristics